## INTEGRATED CIRCUITS



Product specification Supersedes data of 1993 Jun 21 IC23 Data Handbook

1998 Jan 16



## 74ABT640

#### **FEATURES**

- Octal bidirectional bus interface
- 3-State buffers
- Power-up 3-State
- Live insertion/extraction permitted
- Output capability: +64mA/–32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

### DESCRIPTION

The 74ABT640 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT640 device is an octal transceiver featuring inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable ( $\overline{OE}$ ) input for easy cascading and a Direction (DIR) input for direction control.

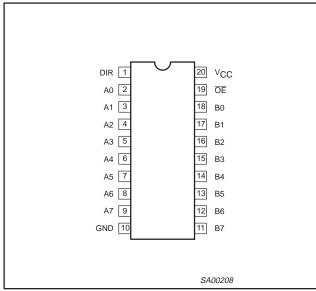
## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	C <sub>L</sub> = 50pF; V <sub>CC</sub> = 5V	3.1	ns
C <sub>IN</sub>	Input capacitance DIR, OE	$V_{I} = 0V \text{ or } V_{CC}$	4	pF
C <sub>I/O</sub>	I/O capacitance	Outputs disabled; $V_O = 0V$ or $V_{CC}$	7	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; $V_{CC}$ =5.5V	50	μΑ

## **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	–40°C to +85°C	74ABT640 N	74ABT640 N	SOT146-1
20-Pin plastic SO	–40°C to +85°C	74ABT640 D	74ABT640 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74ABT640 DB	74ABT640 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +85°C	74ABT640 PW	74ABT640PW DH	SOT360-1

## PIN CONFIGURATION

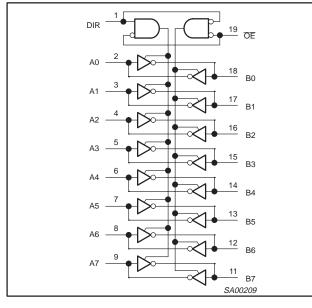


## **PIN DESCRIPTION**

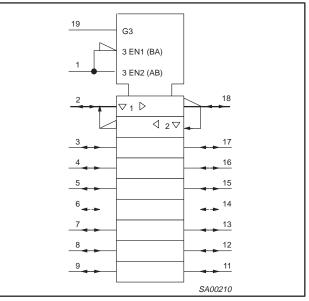
PIN NUMBER	SYMBOL	NAME AND FUNCTION			
1	DIR	Direction control input			
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)			
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)			
19	ŌĒ	Output enable input, B side to A side (active-Low)			
10	GND	Ground (0V)			
20	V <sub>CC</sub>	Positive supply voltage			

## 74ABT640

## LOGIC SYMBOL



## LOGIC SYMBOL (IEEE/IEC)



## **FUNCTION TABLE**

INP	JTS	INPUTS/OUTPUTS				
OE	DIR	An	Bn			
L	L	Bn	Inputs			
L	Н	Inputs	Ān			
н	Х	Z	Z			

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "off" state

### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-18	mA
VI	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>ОК</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
I <sub>OUT</sub>	DC output current	output in Low state	128	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 74ABT640

## **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	ITS	UNIT
		Min	Max	
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
I <sub>ОН</sub>	High-level output current		-32	mA
I <sub>OL</sub>	Low-level output current		64	mA
Δt/Δv	Input transition rise or fall rate	0	5	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

### DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	YMBOL PARAMETER TEST CONDITIONS		TEST CONDITIONS	Tai	<sub>mb</sub> = +25	°C	T <sub>amb</sub> =	–40°C 85°C	UNIT
				Min	Тур	Max	Min	Max	
V <sub>IK</sub>	Input clamp volt	age	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V
			$V_{CC}$ = 4.5V; $I_{OH}$ = –3mA; $V_{I}$ = $V_{IL}$ or $V_{IH}$	2.5	2.9		2.5		V
V <sub>OH</sub>	High-level outpu	ut voltage	$V_{CC}$ = 5.0V; $I_{OH}$ = –3mA; $V_{I}$ = $V_{IL}$ or $V_{IH}$	3.0	3.4		3.0		V
			$V_{CC}$ = 4.5V; $I_{OH}$ = -32mA; $V_I$ = $V_{IL}$ or $V_{IH}$	2.0	2.4		2.0		V
V <sub>OL</sub>	Low-level outpu	t voltage	$V_{CC}$ = 4.5V; $I_{OL}$ = 64mA; $V_{I}$ = $V_{IL}$ or $V_{IH}$		0.42	0.55		0.55	V
l <sub>l</sub>	Input leakage	Control pins	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$		±0.01	±1.0		±1.0	μA
	current	Data pins	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$		±5	±100		±100	μA
I <sub>OFF</sub>	Power-off leakage current		$V_{CC}$ = 0.0V; $V_{I}$ or $V_{O} \leq 4.5V$		±5.0	±100		±100	μA
I <sub>PU</sub> /I <sub>PD</sub>	Power-up/down output current <sup>3</sup>	3-State	$V_{CC}$ = 2.1V; $V_{O}$ = 0.5V; $V_{I}$ = GND or $V_{CC};$ $V_{OE}$ = Don't care		±5.0	±50		±50	μΑ
I <sub>IH</sub> + I <sub>OZH</sub>	3-State output H	ligh current	$V_{CC}$ = 5.5V; $V_{O}$ = 2.7V; $V_{I}$ = $V_{IL}$ or $V_{IH}$		5.0	50		50	μA
I <sub>IL</sub> + I <sub>OZL</sub>	3-State output L	ow current	$V_{CC}$ = 5.5V; $V_{O}$ = 0.5V; $V_{I}$ = $V_{IL}$ or $V_{IH}$		-5.0	-50		-50	μA
I <sub>CEX</sub>	Output High lea	kage current	$V_{CC}$ = 5.5V; $V_{O}$ = 5.5V; $V_{I}$ = GND or $V_{CC}$		5.0	50		50	μA
Ι <sub>Ο</sub>	Output current <sup>1</sup>		V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 2.5V	-50	-100	-180	-50	-180	mA
I <sub>CCH</sub>			$V_{CC}$ = 5.5V; Outputs High, $V_{I}$ = GND or $V_{CC}$		50	250		250	μA
I <sub>CCL</sub>	Quiescent supp	ly current	$V_{CC}$ = 5.5V; Outputs Low, $V_{I}$ = GND or $V_{CC}$		24	30		30	mA
I <sub>CCZ</sub>			$V_{CC}$ = 5.5V; Outputs 3-State; V <sub>I</sub> = GND or V <sub>CC</sub>		50	250		250	μA
ΔI <sub>CC</sub>	Additional supplinput pin <sup>2</sup>	y current per	$V_{CC}$ = 5.5V; one input at 3.4V, other inputs at $V_{CC}$ or GND		0.05	1.5		1.5	mA

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

2. This is the increase in supply current for each input at 3.4V.

<sup>3.</sup> This parameter is valid for any V<sub>CC</sub> between 0V and 2.1V, with a transition time of up to 10msec. From V<sub>CC</sub> = 2.1V to V<sub>CC</sub> = 5V  $\pm$ 10% a transition time of up to 100µsec is permitted.

Product specification

## 74ABT640

### **AC CHARACTERISTICS**

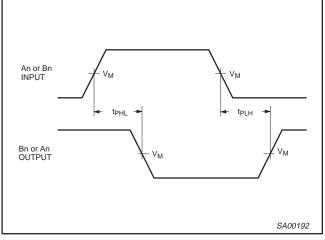
GND = 0V;  $t_R = t_F = 2.5 \text{ns}$ ;  $C_L = 50 \text{pF}$ ,  $R_L = 500 \Omega$ 

					LIMIT	ſS		
SYMBOL	PARAMETER	WAVEFORM	T <sub>a</sub> V	amb = +25° ′ <sub>CC</sub> = +5.0′	C V	$T_{amb} = -40^{\circ}$ $V_{CC} = +5.$	UNIT	
			Min	Тур	Max	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An to Bn or Bn to An	1	1.0 1.5	2.8 3.1	4.2 4.3	1.0 1.5	4.9 4.9	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.5 1.3	3.6 3.2	4.9 5.9	1.5 1.3	5.8 7.3	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low Level	2	2.5 2.0	5.2 4.1	6.5 5.3	2.5 2.0	6.8 5.5	ns

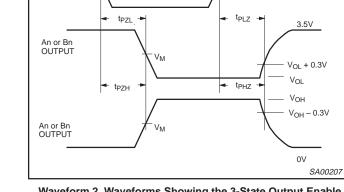
OE INPUT

### **AC WAVEFORMS**

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$ 



Waveform 1. Waveforms Showing the Input to Output Propagation Delays

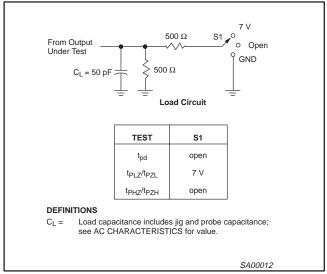


 $\mathsf{V}_\mathsf{M}$ 

Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

Vм

## TEST CIRCUIT AND WAVEFORMS

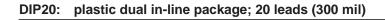


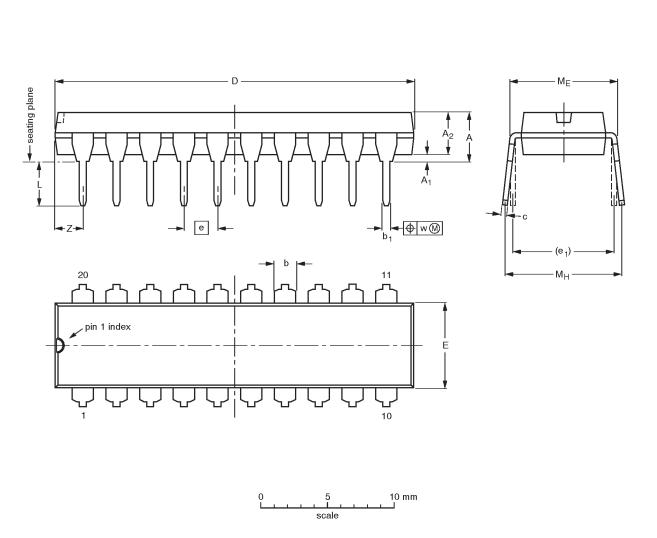
## Product specification

SOT146-1

# Octal transceiver with direction pin, inverting (3-State)

## 74ABT640





### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

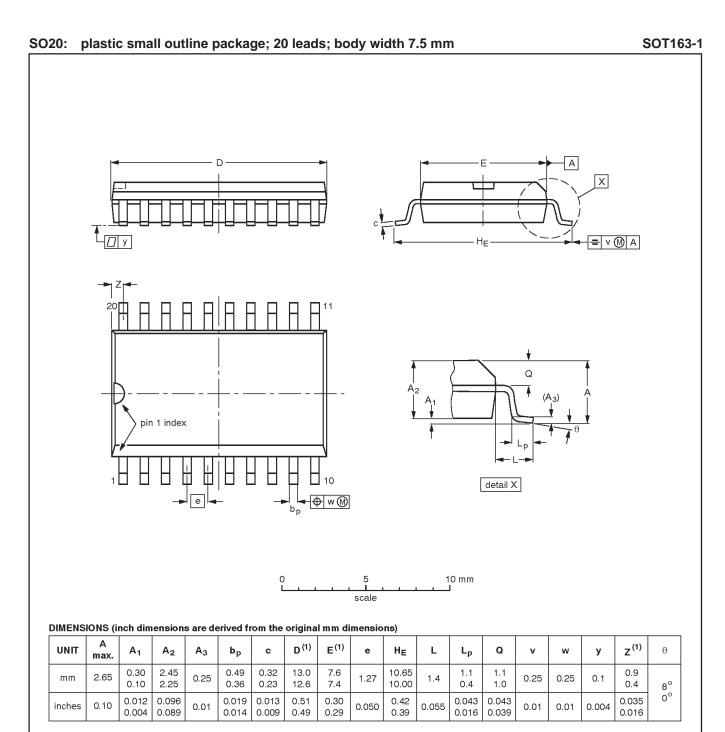
UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	с	р <sup>(1)</sup>	Е <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT146-1			SC603		<del>-92-11-17</del> 95-05-24	

## 74ABT640



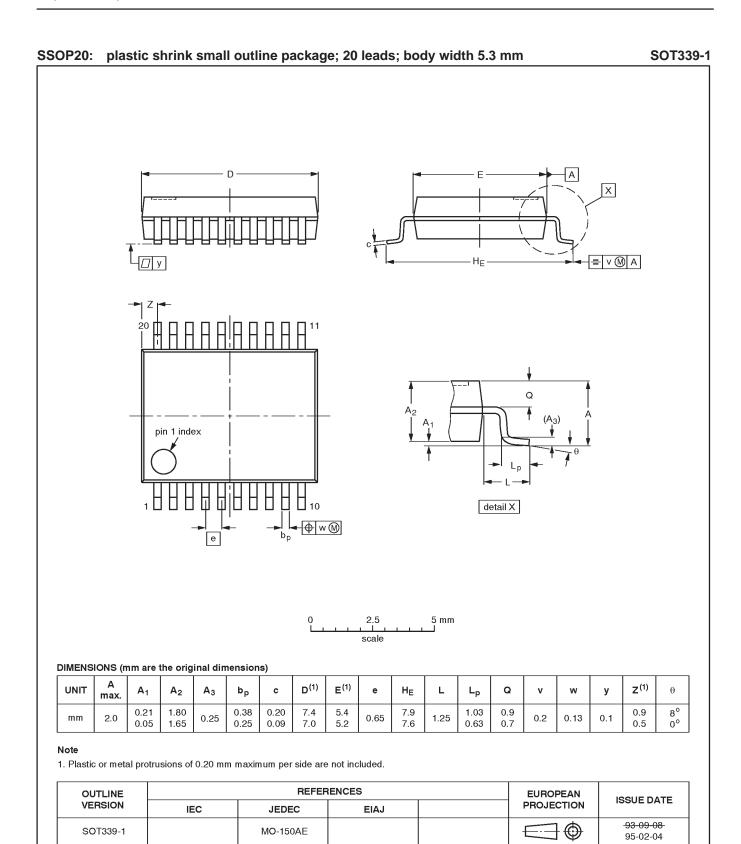
#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013AC			<del>-92-11-17</del> 95-01-24	

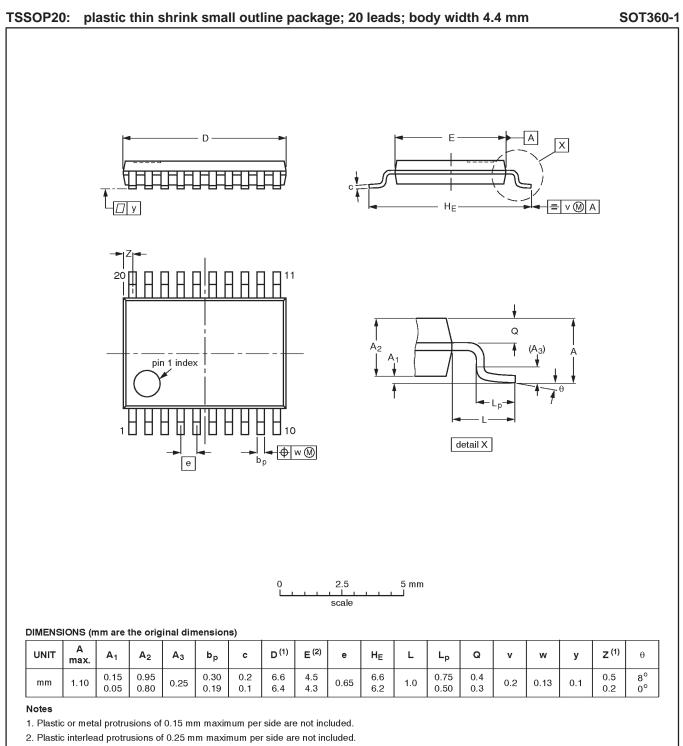
Product specification

74ABT640



Product specification

## 74ABT640



OUTLINE		REFER	ENCES	EUROPEAN			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE		
SOT360-1		MO-153AC			<del>-93-06-16</del> 95-02-04		

### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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